

A highly-ordered, high mobility organic semiconductor grown from a mesophase: A test of polaron band theory

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Abstract

We find that the hole mobility of the crystal smectic phases of the liquid crystal 1,4-di-(5-n-tridecylthien-2-yl)-benzene increases exponentially with decreasing temperature. While qualitatively consistent with transport via polaron bands, we find that it is quantitatively difficult to explain the behavior with physically realistic parameters. In particular, the data demand either quite large typical optical phonon frequencies and/or phonon bandwidths. We also find evidence that an unusually highly ordered smectic-F phase templates the formation of lower temperature highly crystalline smectic phases, which may have implications for device development.

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I. INTRODUCTION

Organic semiconductors are a large, promising group of electronic materials for applications in photovoltaics, flexible, low-cost electronics, and sensor applications. Thermotropic liquid crystalline organic semiconductors (LCOSCs) are a particularly interesting subclass of these compounds[1, 2]. LCOSCs are typically composed of highly conjugated molecular cores with long, relatively saturated "tails" that favor thermodynamic phases with partial molecular ordering[3]. As with all liquid crystals, LCOSCs may form a variety of phases as a function of temperature, from highly disordered nematic high-T states to "plastic crystal" low-T smectic phases. It is the intrinsic, generally dynamic disorder of LC phases that differentiate LCOSCs from more conventional crystalline organic semiconductors. Indeed, it is this disorder that offers tremendous potential advantages in practical applications: by taking advantage of the high-T, more "liquid-like" phases, LCOSCs may in principle be processed with ease into highly ordered semiconducting films. This work explores the electronic and structural properties of a technologically interesting LCOSC in which the structures of the low-T, high-mobility phases are templated by those of the higher-T, more disordered states. The behavior of the charge mobility of organic semiconductors as a function of temperature and electric field, $\mu(T, E)$, may change qualitatively based on, e.g., the polarizability of the host lattice, the phonon spectrum, and the electronic bandwidth of the valence (for hole transport) or conduction (electron transport) band. Many refinements of the basic ideas of Holstein[4] have been developed, dealing with both non-adiabatic[5] (hopping conduction with activated-like temperature dependence) and adiabatic[6] (tunneling-dominated or band-like) transport. Here, we report studies of a material that exhibits polaron band behavior. However, while qualitatively consistent with the model, the data exhibit an inconsistency (exponential growth of mobility with decreasing temperature), the resolution of which appears to require parameter values bordering on the unphysical. The rapid increase of mobility at lower T also makes related systems of real interest for, e.g., thin-film transistor fabrication. Of practical interest are the facts that the crystal smectic F mesophase exhibits very long correlation lengths (i.e., is highly ordered) and that the more ordered crystal smectic G phase appears to inherit this order and therefore easily forms domains large enough to transport holes without a great deal of trapping at boundaries.

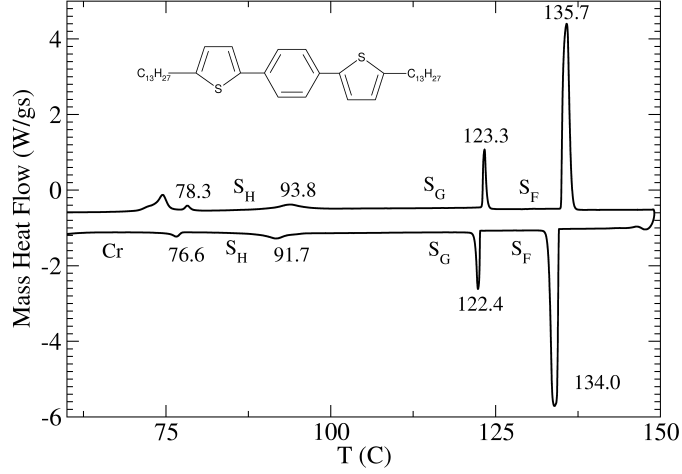
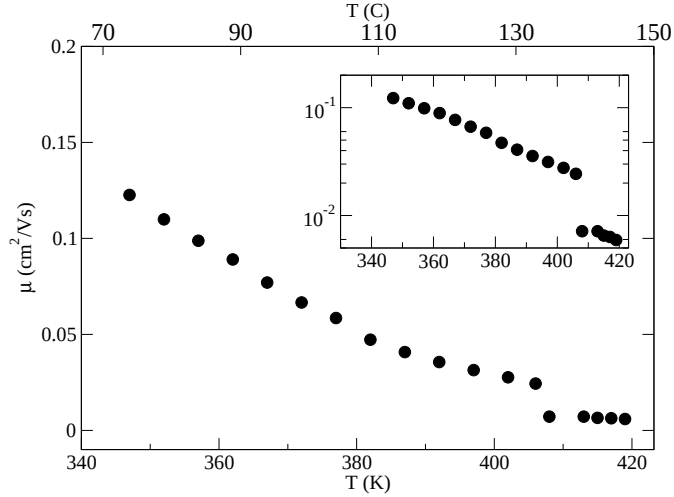


FIG. 1. Differential Scanning Calorimetry data. The smectic H, G, and F mesophases and a crystal are labeled. Inset: Structural formula for the TTBB mesogen.

II. MATERIAL AND TECHNIQUES

Our material is built around a thiophene-benzene-thiophene core with alkyl tails. A detailed description of the synthesis and purification of the mesogen, 1,4-di-(5-n-tridecylthien-2-yl)-benzene (TTBB), may be found in the supplementary information at EPAPS. Powder x-ray studies were performed at the Advanced Photon Source at Argonne National Laboratory using 0.765335 Å photons with the sample contained in a Lindeman capillary. Hole time-of-flight (TOF) mobility data were collected using 10 ns Nd:YAG frequency-doubled stimulated Raman shifted laser pulses to photoexcite a sample contained in an ITO/glass capacitor[7] of thickness ≈ 20 μm . Laser pulse intensities were kept low to avoid space-charge effects. The temperature range over which we could collect data was limited on the low end by trapping and on the high end by melting of the sample into the isotropic phase. Electron TOF traces were too dispersive to allow for mobility measurement. Differential scanning calorimetry (Fig. 1), powder x-ray diffraction (see below), and polarized light microscopy indicate the phase sequence Cr 76.6 SmH 91.7 SmG 122.4 SmF 134.0 I (on cooling)[8](the latter data may be found in the supplemental information).



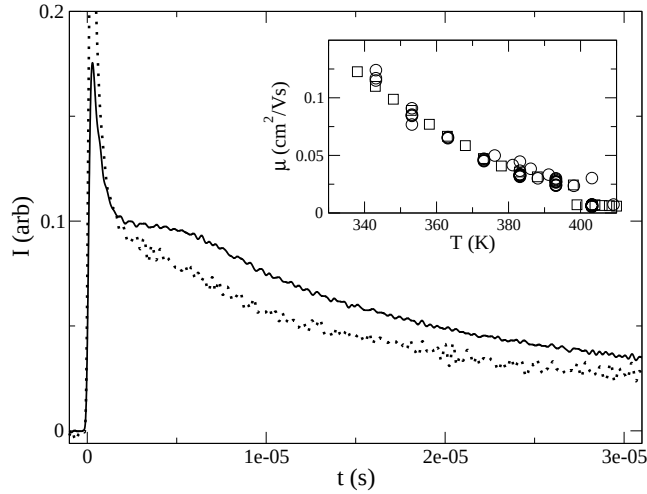


FIG. 3. The mobility derived from log-log plots of highly dispersive traces at fixed field (squares) are essentially the same as those from far less dispersive transients (circles, at various electric fields). Inset: Example more and less dispersive TOF transients at 90 °C.

extremely dispersive transients (where log-log plots are needed to see the inflection point) and those extracted from far less dispersive data that clearly show plateaus on linear graphs. This is shown in Fig. 3, where we plot the data of Fig. 2 with a set of mobilities extracted from wide variety of far less dispersive data sets at many voltages- the agreement is excellent throughout (as we will show in detail, below, μ is independent of field). This is not what is expected in detailed models of hopping conduction in the presence of disorder[13], and is evidence that a different mechanism is operative here.

The isotropic to SmF transition has a major effect on the mobility, with μ increasing a factor of 3.4 as the sample enters the mesophase. As T falls, the mobility sharply yet smoothly increases, to a maximum $> 0.1 \text{ cm}^2/\text{Vs}$ at the lowest temperature measured. Such large mobilities generally arise from a combination of two factors: firstly, favorable single-molecule physics (hinted at in the large value of μ in the isotropic phase, in which intermolecular geometries are averaged over) and secondly, a high degree of long-range ordering. In Fig. 4, we show powder diffraction data in the SmF phase, which imply very large positional order correlation lengths, both orthogonal (112.2 nm) and parallel (10.85 nm) to the smectic planes. For comparison, the maximum correlations lengths measured in magnetically-aligned free-standing films in the SmF phase of the liquid crystal TB10A[14]

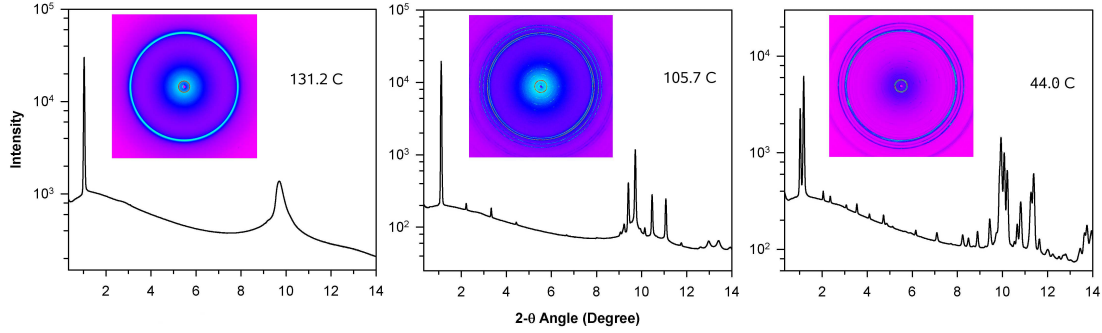


FIG. 4. Powder diffraction results for (left to right) the SmF, SmG and *Cr* phases. Note both the high degree of order in the mesophase and the similarity of the structures of both smectic phases and the crystal.

in either direction are less than 20 nm (albeit only slightly below the SmI to SmF transition temperature). Correlations have also been measured across the SmF to SmG transition (i.e., similar to TTB) in the liquid crystal HBHA by Kumar[15], who found in-plane lengths of ~ 20 nm in the SmF phase, increasing to ~ 150 nm in the SmG phase. TTB, therefore, appears to be very ordered indeed in the high temperature SmF phase.

Surprisingly, there are first-order structural transitions at $T_{SmF} \rightarrow T_{SmG} \approx 395$ K and $T_{SmG} \rightarrow T_{SmH} \approx 365$ K, with little (if any) signature in the mobility. The SmF phase is characterized by hexagonally-ordered tilted layers, typically with little inter-layer correlations (though the layers do not readily rotate relative to one another)[16]. The SmG phase, on the other hand, is a 3-dimensional pseudo-hexagonal crystal phase where the (tilted) molecules are relatively free to rotate about their long axis. Since μ does not suddenly change at the F-G transition, we conclude that the relative ordering of the layers is not as important in hole transport as the ordering within layers. The SmH phase is a monoclinic crystal where molecules can only rotate by 180° (i.e., they may flip) about their long axis. It therefore differs from the SmG phase in symmetry (four nearest neighbors rather than six) and in the rotational freedom of the mesogens. However, as at the F-G transition, there is no obvious jump in mobility at the transition. (There may, however be a slight change in the slope of the data at this transition, though the limited temperature range makes it difficult to judge - see the inset to figure 2.) Interestingly, X-ray studies of SmF-SmG-SmH transitions[17] in terephthal-bis-(4n)-alkylanilines find that the layer spacing changes very little at both the SmF-SmG, and SmG-SmH transitions. (Note that, at the time this

reference was written, the G phase was referred to as the H phase, and *vice-versa*). The molecular tilt angle is also essentially constant through the SmF-SmG phase change. In other words, the actual structural changes that occur at these phase boundaries are minor. If these facts remain true for our material, they offer a natural explanation of both the lack of jumps in mobility at phase boundaries, and of the seemingly uniform behavior of $\mu(T)$ over the entire temperature range. In light of this information, and given the smoothness of the mobility as a function of T , we choose to describe the entire crystal smectic temperature range using a single theoretical approach, keeping in mind that there may be quantitative changes in behavior unique to each phase.

Our data in the crystal smectic phases may be well described by either a power-law ($\mu \sim T^{-n}$, not shown) or by an exponential, $\mu \sim \exp(-\alpha T)$, shown in the inset to Fig 2. Theories of polaron hopping[6, 18] predict that at high temperatures

$$\mu(T) \propto \frac{1}{T^{3/2}} \exp(-E_{pol}/2kT) \quad (1)$$

where E_{pol} is the small-polaron binding energy. At very high T , $kT \gg E_{pol}$ (i.e., hot enough to dissociate polarons), this gives $\mu \sim T^{-1.5}$. It is very unlikely that our data are in this regime, since typical polaron binding energies[18] are several tens of meV, or several times kT . Indeed, we have computed[19] E_{pol} for a molecule corresponding to the thiophene-benzene-thiophene core of our liquid crystal (with no tails) and find $E_{pol} = 192$ meV, far greater than thermal energies. In any case, we find a best-fit power $n \approx 10$, far greater than the 1.5 or the $n \sim 2 - 4$ empirically found in other organics[18, 20] (we note that the SmF, SmG, and SmH phases, if analyzed separately, all independently demand very large slopes). We therefore conclude that polaron hopping theories are inapplicable to our results.

A general result of polaron band theories, such as that described by Silbey and Munn[6], and present in the early theory of Holstein[4], is that there is a narrow crossover temperature regime (characteristic temperature T_a) between non-adiabatic and adiabatic conduction, with the latter taking over at low T . The crossover temperature is critical in describing our results: above T_a , $\mu(T)$ has positive slope while below T_a , the mobility typically has negative slope and can exhibit qualitatively exponential behavior. Four parameters control both T_a and the shape of $\mu(T)$: the electron bandwidth, B , the characteristic optical phonon frequency, ω , the phonon bandwidth, Δ , and the dimensionless electron-phonon coupling,

g . The predicted mobility, both above and below T_a , is given by[6]

$$\mu(T) = \mu_H + \mu_T \quad (2)$$

$$\mu_H = \frac{\beta e a^2}{\pi^{1/2} \hbar [I_0(y) - 1]} \frac{\tilde{B}^2 + \Gamma^2}{\sqrt{\tilde{B}^2 + 2\Gamma^2}} \quad (3)$$

$$\mu_T = \frac{\beta e a^2}{4\hbar} \pi^{1/2} [I_0(y) - 1] \frac{\tilde{B}^2}{\sqrt{2\tilde{B}^2 + \Gamma^2}} \exp\{-\frac{1}{4}\beta^2 \tilde{B}^4 / (2\tilde{B}^2 + \Gamma^2)\} \quad (4)$$

where

$$\tilde{B} = B \exp\{-g^2 / \tanh(\beta \hbar \omega / 2)\} \quad (5)$$

$$y = 4g^2 \sqrt{n(n+1)} \quad (6)$$

with μ_H and μ_T the hopping and tunneling contributions to mobility, $\beta = 1/k_B T$, and a the intermolecular distance. $\tilde{B}$ is the renormalized (Huang-Rhys) polaron bandwidth[4] which decreases sharply with increasing temperature, Γ is a modified phonon bandwidth[6], and n is the phonon distribution function, $n = 1/[\exp(\beta \hbar \omega) - 1]$. The hyperbolic Bessel function $I_0(y)$ is a sharply increasing function of its argument and therefore of T ($y \sim n$ and n increases with T). We use the x-ray derived value of $a=4.2$ nm (i.e., we assume transport is dominated by motion orthogonal to the smectic layering). Note that these expressions provide a prediction for the mobility in absolute units. Given the small region of temperature (even though we consider the SmF, SmG and SmH phases collectively in our analysis), it is impossible to constrain all four of the parameters. However, we find that, in order to move the low- T quasi-exponential region of μ to the experimental temperature range, and to account for the measured values of mobility, the model requires large coupling $g \geq 1$ and small raw electronic bandwidth $B \ll \omega$. (The data do not constrain B except that they require $B/\omega \ll 1$.) In this regime, we must then have either *large phonon bandwidth* $\Delta > \hbar \omega$ and/or *high center frequency* ω . This is logical - the value of the crossover temperature T_a is set partly by the phonon energies the system supports, i.e., either by ω itself or by the high energy tail of the Gaussian distribution whose width is set by Δ . The model, however, is limited to $\Delta/\omega < 1$ (so that the phonon distribution can be modeled as a Gaussian[6]). Letting the phonon bandwidth take on a maximal value, say $\Delta/\hbar \omega = 0.5$, we find that the data may be fit, albeit with $\omega/k_B \approx 440$ K. Typical acenes and simple aromatics like perylene have experimentally measured phonon bandwidths centered around 200 K or less (an oft-used approximate value is 100 $\text{cm}^{-1} \approx 150$ K). It is hard to understand why a relatively flexible molecule like ours would have a much stiffer lattice than these fully aromatic materials. We therefore conclude

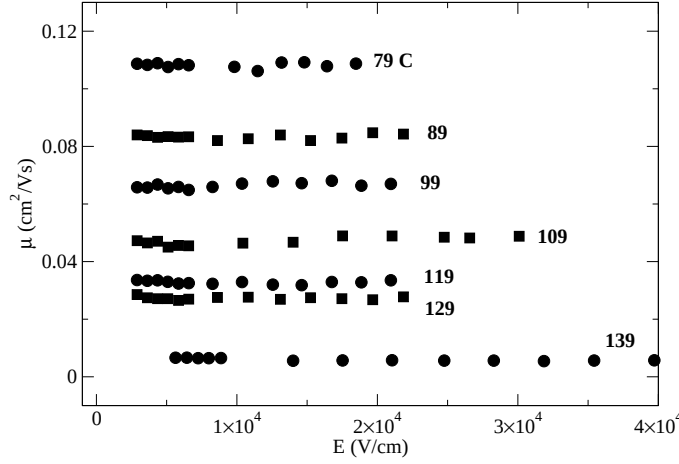


FIG. 5. Mobility as a function of electric field at various temperatures. At each temperature, the mobility appears to be ohmic, i.e., independent of field.

that the present model is quantitatively incorrect. Given the simplifications inherent in the theory (greatly simplified phonon band structure, including the limitations on Δ , the assumed isotropy of the phonon spectrum, etc.), this is not too surprising. We note that more complete theories including non-local electron-phonon interactions[21, 22] are unlikely to resolve our difficulties since they seem to *reduce* the slope at low T, while our data demand moving the regime of quasi-exponential growth to higher temperature. Given the large mobilities in this material, along with the presumed softness of the highly-ordered smectic “lattice”, perhaps a more promising direction is supplied by theories of intermediate bandwidth organic semiconductors, such as those explored by Kenkre and coworkers[23].

The electric field dependence of the mobility is a powerful probe of the microscopics. In the case of hopping conduction[5], $\mu(E)$ can be super-exponential. On the contrary, we find the E is irrelevant. In Fig. 5, we show the hole mobility over a wide range of field and temperatures in each phase. In every case, μ is essentially independent of field. This is consistent with a band model. We note that we do not observe any sign of a drop in mobility at large fields that would indicate hot-carrier effects.

There are a number of other highly-ordered smectics that have been studied as semiconductors[24–28], some (though by no means all) with mobilities in the $0.1 \text{ cm}^2/\text{Vs}$ range. To our knowledge, however, this is the first smectic H material so studied, and the first very high mobility

smectic with polaron band-like transport. It is interesting and potentially of practical utility that the nearly crystalline H phase of 1,4-di-(5-n-tridecylthien-2-yl)-benzene supports high-quality hole transport in our 20 μm cells, since, in our experience, "true" crystal phases grown from smectics usually have too much structural disorder (and therefore trapping) to even show measurable TOF transients. One possible explanation is that the highest temperature crystal smectic, SmG, inherits the impressive long-range order of the mesophase, both orthogonal and parallel to the smectic planes, which in turn templates the H phase. Very similar behavior, in which oligothiophenes with SmF phases templated a polycrystal supporting high mobility conduction, has previously been reported, though with quite different temperature dependences than our results[11, 29]. (Unfortunately, no correlation lengths were reported for comparison with our material. This would be a worthwhile direction for further work.) The powder diffraction results shown in Fig. 4 suggest that the SmF state templates the structure of the SmG (and eventually the SmH) highly crystalline smectic phases, which presumably forms in larger, better ordered grains due to the order of the higher temperature smectic. This presents a very interesting technological advantage of these crystal smectics: thin samples of a high-mobility essentially crystalline organic may be grown with large-grained structure by using a less-ordered smectic phase as a template. Indeed, by using standard methods to align the liquid crystal phase (appropriately rubbed polyimide alignment layers, magnetic and electric fields, etc.), it may be possible to stabilize a fully crystalline thin film *via* the mesophase. The implications for device (for example, thin film transistor) development, where a high-mobility film must be produced, preferably at low temperatures, are obvious. Another interesting possibility is to use the mesophase to anneal away damage in the semiconductor and then to re-crystallize the ordered film *in-situ*.

This system is not the first liquid crystal with a thiophene-benzene-thiophene core found to have a high mobility. In 2005 Oikawa *et al.*[30] measured $\mu(T)$ in the C_8 analog of our material and found similar mobilities, though the mobility increase with decreasing T was less pronounced. Whether this is due to an intrinsic difference in the materials or to cell thickness (they used 15.9 μm), alignment, or cooling rate is unknown. The authors of ref. [30] found the phase assignment I 145 Sm 1 87 Sm 2 71 Sm 3 47 Cr , i.e., three unidentified smectic phases followed by a crystal phase on cooling. This is similar to our results. Interestingly, Oikawa *et al.* found large ($\sim 0.1 \text{ cm}^2/\text{Vs}$) mobilities in the lower mesophases, and much higher values of μ in the highest temperature smectic Sm1 phase than we find

in our SmF regime. Obviously, further mobility and structural studies (including phase assignment) of this series are warranted. Duzhko *et al.*[20] found evidence for polaron band transport in a very different mesogen, the hexapentyloxytriphenylene (HAT5), a discotic material with a mobility at least three orders of magnitude smaller than that of the present material’s SmH phase. Apparently, charge transport via renormalized polaronic bands is a fairly generic occurrence in organics of widely differing morphology.

IV. CONCLUSION

Our material, 1,4-di-(5-n-tridecylthien-2-yl)-benzene, appears to be a prototype narrow polaron band semiconductor, which presents opportunities for refining the relevant theories. The principal theoretical question is, why is “the low temperature regime” accessed for T greater than the likely phonon frequencies? We also find that the high mobility *essentially crystalline* phases may be reliably formed in thin films by using the high temperature liquid crystalline state as a template, opening interesting technological vistas.

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